

August 11 (Sun)	K-C-J Joint Workshop	204+205
10:00~17:00		
10:30~10:40	10	Opening Remarks from Korea, China, and Japan
Technical Session 1 (Chair: Hae-Seok Lee, Korea University, Korea) : Technologies and Policies in Korea, China, and Japan		
10:30~10:50	20	Seung Yeop MYOUNG, KETEP, Korea
10:50~11:10	20	Meiqin MAO, Hefei University of Technology, China
11:10~11:30	20	Yuzura UEDA, Tokyo University of Science, Japan
Technical Session 2 (Chair: China) : Recent Progress in Crystalline Si PV		
11:30~11:50	20	Hee-Eun SONG, KIER, Korea
11:50~12:10	20	Noritaka USAMI, Nagoya University, Japan
12:10~13:30	80	Lunch
Technical Session 3 (Chair: Min Jae Ko, Hanyang University, Korea) : Recent Progress in Perovskite based PV		
13:30~13:50	20	Beom Soo KIM, KRICT, Korea
13:50~14:10	20	Meicheng LI, North China Electric Power University, China
14:10~14:30	20	Takuro MURAKAMI, AIST, Japan
14:30~14:50	20	Seok-In NA, Jeonbuk National University, Korea
14:50~15:10	20	Makoto KONAGAI, Tokyo City University, Japan
15:10~15:30	20	Coffee Break
Technical Session 4 (Chair: Japan) : Recent Progress in Inorganic Thin Film based PV		
15:30~15:50	20	Ki HWAN KIM, KIER, Korea
15:50~16:10	20	Qingbao MENG, CAS, China
16:10~16:30	20	Yositaro NOSE, Kyoto University, Japan
16:30~16:50	20	Jeong-Hyun JEONG, KIST, Korea
16:50~17:10	20	Kosuke O. HARA, University of Yamanashi, Japan
17:10~17:30	20	A time for collective reflection and future relationship building
18:00	-	Banquet with Welcome Reception (GPVC)